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Permalink https://escholarship.org/uc/item/1hm0f3rp

Journal ACS Nano, 19(3)

ISSN 1936-0851

Authors

Loni, Elham Majed, Ahmad Zhang, Shengjie <u>et al.</u>

Publication Date 2025-01-28

DOI

10.1021/acsnano.4c09903

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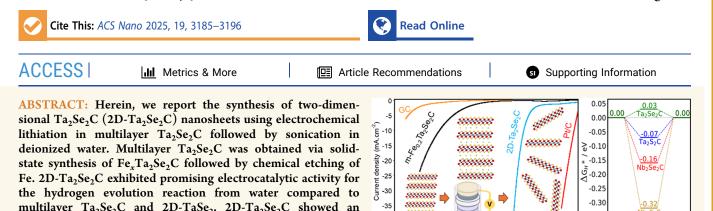


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Two-Dimensional Tantalum Carbo-Selenide for Hydrogen Evolution

Elham Loni, Ahmad Majed, Shengjie Zhang, Hari H. S. Thangavelu, Chaochao Dun, Anika Tabassum, Karamullah Eisawi, Jeffrey J. Urban, Per O. Å. Persson, Matthew M. Montemore, and Michael Naguib*



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overpotential at 10 mA·cm⁻² (η_{10}) of 264 mV, a Tafel slope of -40 H⁺+e⁻ H^{*} 1/2 H₂ Reaction Coordinate -0.8 -0.2 0.6 -0.4 Potential vs. RHE (V) 91 mV·dec⁻¹, and an electrochemically active surface area of 17.61 $m_{ECSA}^{2} \cdot g_{catalyst}^{-1}$. The high performance could be attributed to the large surface area of single sheets which hence maximizes the number of exposed catalytic sites and increased density of vacancies, observed with transmission electron microscopy, during synthesis and processing.

KEYWORDS: two-dimensional materials, transition metal carbo-chalcogenides, delamination, hydrogen evolution, electrocatalyst

Transition metal dichalcogenides (TMDs) are layered structures consisting of a core transition metal layer bonded to two surface layers of chalcogen atoms with a general chemical formula of MX₂ (M: transition metal, X: chalcogen such as S, Se, or Te).¹ These materials have direct bandgaps and interesting electronic and optical properties, which make them suitable candidates for various applications such as electronics² and optoelectronics.³ Monolayers of TMDs were shown to be catalytically active with different electrical properties ranging from insulating to semiconducting and metallic, leading to their applications in electrochemical energy storage,⁴ electrocatalysis,^{5,6} heterogeneous catalysis,⁷ and photocatalysis.⁸ Especially 1T and 1T' phases showed high electrical conductivity and have been reported as outstanding electrocatalysts for the hydrogen evolution reactions (HERs). For example, Lukowski et al.⁹ reported the synthesis of 1T-MoS₂ using lithium intercalation and chemical exfoliation of $2H-MoS_2$ that showed a low overpotential of 187 mV for a current density of 10 mA·cm⁻². In another study, Voiry et al. reported exfoliation of 1T-MoS₂ nanosheets with a Tafel slope of 40 mV·dec^{-1,10} TMDs are known to be earth-abundant materials as potential replacements for noble metal-based catalysts in the electrocatalytic HER,^{5,11,12} due to their unique atomic structure and optimized active site density and surface area. However, these 2D-TMDs suffer from poor stability when exposed to ambient conditions. These materials, particularly in their monolayer or few-layer forms, are prone

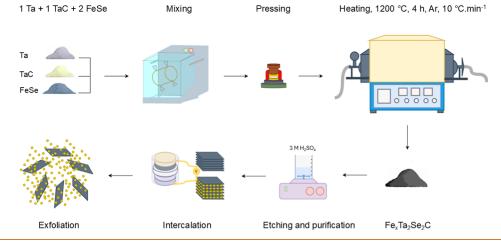
multilayer Ta₂Se₂C and 2D-TaSe₂. 2D-Ta₂Se₂C showed an

to oxidation and degradation upon exposure to air and moisture, which can significantly alter their electronic properties and hinder their performance in different applications.¹³ For example, oxidation can result in the formation of metal oxides, disrupting the pristine crystalline structure and impairing conductivity. Additionally, defect sites in the crystal lattice, such as vacancies or grain boundaries, can exacerbate the degradation process, making these materials more susceptible to environmental stressors. Various approaches, such as encapsulation with stable 2D materials (e.g., graphene or hexagonal boron nitride) or functionalization with protective coatings, are being explored to mitigate these stability issues. Improving the stability of 2D-TMDs remains a critical challenge for their use in long-term and practical applications like flexible electronics and optoelectronic devices.^{13,14} An alternative approach is the synthesis of new 2D materials that have high electrical conductivity, high catalytic activity, and higher stability at the same time. For instance, if we can synthesize 2D layered materials with a

Received: July 22, 2024 Revised: December 26, 2024 Accepted: December 30, 2024 Published: January 16, 2025







Scheme 1. Schematic Illustration of the Synthesis Procedure of 2D-Ta₂Se₂C

chalcogenide surface like TMDs and the carbide core of MXenes,¹⁵ the resulting material could have extraordinary electrocatalytic performance owing to the combination of high catalytic activity, electrical conductivity, and high stability.

Recently, we reported on the large-scale synthesis of layered transition metal carbo-chalcogenides (TMCCs) and their exfoliation, including 2D-Ta₂S₂C and Nb₂S₂C, with superconductivity characteristics, high elastic constants, and promising performance as electrode materials in Li-ion batteries. TMCCs (M₂X₂C; M: transition metal, X: chalcogen, C: carbon) are a family that exhibits different properties and applications by tuning their composition.¹⁶ This family has the potential to expand by using different transition metals, as well as different chalcogens. The first successful synthesis of the TMCC multilayer was reported for Ta₂S₂C in 1970 by Beckmann et al.¹⁷ Later, more reports on the synthesis of TMCCs were published, such as M_xNb₂S₂C (M: V, Cr, Mn, Fe, Co, Ni, Cu)¹⁸ and Nb₂S₂C.¹⁹ Recently, many *ab initio* calculation studies have focused on predicting the properties of various TMCCs.²⁰⁻²⁵ These materials have layered structures with strong covalent intralayer bonding and relatively weak van der Waals out-of-plane bonding,²⁵ which makes their exfoliation process possible, as reported for the first time for 2D-Ta₂S₂C and Nb₂S₂C by Majed et al. in 2022.¹⁶

Although theoretical calculations have predicted the stability and properties of many 2D-TMCCs, most experimental studies have only focused on structures with sulfur as the chalcogen. There are still many TMCCs that have never been synthesized or reported, such as those including selenium, tellurium, and/ or a solid solution of sulfur, selenium, and/or tellurium.

Herein, we report the synthesis of 2D Ta₂Se₂C. As shown in Scheme 1, multilayered Ta₂Se₂C was produced by the solidstate synthesis of Fe_xTa₂Se₂C, followed by chemical etching of iron. To exfoliate these materials, lithium (Li) was electrochemically intercalated between the layers (electrochemical cell schematic is shown in Scheme S1). The Li-intercalated Ta₂Se₂C was then submerged in water and sonicated to induce swelling and exfoliation of the layers. 2D-Ta₂Se₂C exhibited superior performance as an electrocatalyst for HER compared to their multilayer counterparts. Density functional theory (DFT) calculations were performed to predict the possible active sites of Ta₂Se₂C and three other TMCCs for comparison.

RESULTS AND DISCUSSION

Characterization of Materials. Figure 1a shows the X-ray diffraction (XRD) patterns of the as-synthesized, etched, lithiated, and delaminated samples. FeSe was used as a source for Se to enable synthesis at temperatures above the boiling point of Se, similar to our previous work on Ta₂S₂C,¹⁶ where FeS was used as a source for S and similar to what Chen et al.²⁶ reported for Ti₂SC. This approach allowed us to use a tube furnace at ambient pressure, avoiding the need to seal the precursors in quartz tubes under vacuum and limiting the heating to temperatures below 1200 °C. Solid-state synthesis of $Fe_xTa_2Se_2C$ with the highest possible purity was crucial for the successful synthesis of the corresponding multilayer and delaminated Ta₂Se₂C. Details on the different synthesis parameters (precursors composition, time, and temperature) considered in the synthesis of Fe_xTa₂Se₂C are provided in Supporting Information (Table S1 and Figure S1). We found that the optimum conditions for achieving the highest content of Fe_xTa₂Se₂C, relative to the secondary phases of Fe, TaC, and Fe_rTaSe_2 , are a molar ratio of Ta/TaC/FeSe = 1.0:1.0:2.0and a heating to 1200 °C for 4 h under continuous Ar flow. A characteristic XRD peak for $Fe_rTa_2Se_2C$ with the P3m1 space group was found at a 2θ of ~9.96°, which is very close to what was reported for $Fe_xTa_2S_2C$.¹⁶

To remove the secondary phase of iron as well as intercalated iron from between the layers, we used a H_2SO_4 treatment. To confirm the removal of Fe, we used an EDS analysis (Table S3). The results showed a drop in the Fe: Ta atomic ratio from 1.00:1.00 to 0.09:1.00 after H_2SO_4 treatment, proving Fe was removed mostly from the sample. Hence, $Fe_{0.2}Ta_2Se_2C$ is used as the chemical formula for the multilayer sample after etching. Scanning electron microscopy (SEM) images of the particles before (Figure S4a,b) and after (Figure S4c,d) etching showed that both samples exhibit layered morphologies.

Predicting that both Ta_2Se_2C and Ta_2S_2C have similar crystal structures but slightly different lattice parameters, they are expected to exhibit similar XRD patterns with slight shifts in the diffraction peaks' positions. Thus, we used the structure of the Ta_2S_2C phase (PDF#00–024–1258) and replaced S with Se to predict the XRD pattern of Ta_2Se_2C . Using Bragg's law, the d_{spacing} of the different crystallographic planes in Ta_2Se_2C was calculated, and from there, the lattice parameters were calculated. The *a* and *c* lattice parameters were calculated

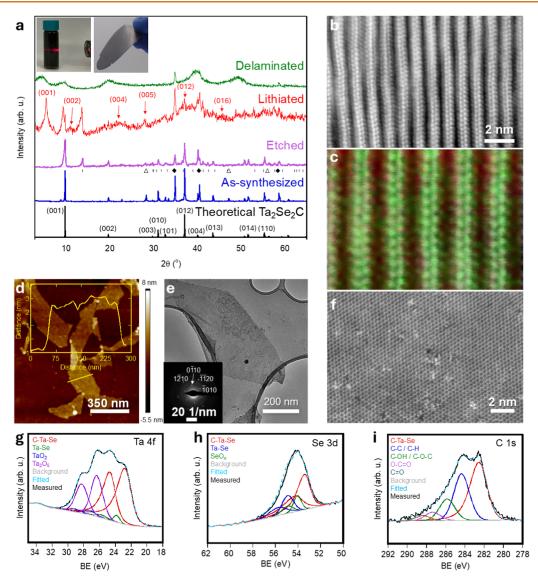


Figure 1. (a) XRD patterns of theoretical Ta_2Se_2C (black) and experimentally measured as-synthesized multilayer $Fe_xTa_2Se_2C$ before (blue) and after (purple) etching, then lithiated (red), and delaminated (green) Ta_2Se_2C . The peaks identified by \blacklozenge indicate peaks for the TaC phase (PDF#00-035-0801), | indicate peaks for the TaSe₂ phase (PDF#21-1200), and Δ referred to Si used as reference. Insets: left, the Tyndall effect of the colloidal dispersion after delamination, and right, free-standing paper. (b) HAADF-STEM image of Ta_2Se_2C and (c) its corresponding EELS map overlay (green: Ta, red: Se), (d) AFM image of the 2D-Ta_2Se_2C few-layer sheets. Inset: height profile along the identified yellow line. (e) TEM image of 2D-Ta_2Se_2C single sheets. Inset: corresponding SAED pattern. (f) Atomically resolved STEM planview image of the 2D-Ta_2Se_2C. (g-i) XPS spectra of the Ta 4f, C 1s, and Se 3d regions, respectively, for 2D-Ta_2Se_2C.

to be 3.29 and 8.93 \pm 0.05 Å, respectively. The XRD pattern based on these calculated lattice parameters was simulated using VESTA. The details for the peaks' positions and their corresponding crystallographic planes for the m-Fe_{0.2}Ta₂Se₂C sample and the calculated data are provided in Table S2. To obtain a precise quantification for the phases present in the sample synthesized by the solid-state procedure as well as the lattice parameters, Rietveld refinement was employed (Supporting Information). According to the Rietveld refinement results, the c-lattice parameter stayed almost unchanged after the H₂SO₄ treatment ($\Delta c \approx 0.02$ Å decrease). We anticipated a decrease in the interlayer spacing after etching due to the removal of the Fe atoms from between the Ta₂Se₂C layers without the formation of new surface terminations as Ta atoms are already terminated by Se during the solid-state synthesis. This contrasts with typical 2D MXenes' synthesis, where the etching process (e.g., removal of Al from the Ti_2AlC

MAX phase to form MXene) is accompanied by the introduction of new surface terminations, such as -OH, -O, or -F groups, which leads to an increase in interlayer spacing compared to the parent MAX phases. The behavior of Fe-intercalated Ta₂Se₂C is predicted to be more analogous to that of intercalated MXenes rather than MAX phases. For intercalated MXenes, deintercalation results in a decrease in interlayer spacing.^{27,28} The small change in the *c*-lattice parameter after H₂SO₄ treatment suggests that the presence of a small amount of iron might be sufficient to maintain the interlayer spacing for the Ta₂Se₂C structure; similar behavior was reported for intercalated 2D materials where a small amount of intercalants can act as pillars maintaining the interlayer spacing.^{27–30}

XRD after etching revealed a more pronounced peak at 2θ of 13.86° that can be assigned to TaSe₂ (PDF#21–1200). This

phase already existed in the $Fe_xTa_2Se_2C$ sample, but after etching and purification, its peaks grew in intensity.

A high-resolution cross-sectional high-angle annular dark field (HAADF)-scanning transmission electron microscopy (STEM) image of a m-Fe_{0.2}Ta₂Se₂C particle together with a corresponding electron energy loss spectroscopy (EELS) elemental map overlay are shown in Figure 1b,c. These images illustrate layered sheets that consist of two atomic layers of tantalum sandwiched between two atomic layers of selenium. The EELS quantification revealed a Ta: Se molar ratio of 2.0:1.8 (Table S4 and Figure S5a), where the deviation from the 2.0:2.0 ratio can be explained by the formation of Se vacancies during acid etching. The interlayer spacing determined from the HAADF-STEM image was found to be 0.98 ± 0.02 nm. The slight difference between TEM (0.98 nm) and XRD (0.89 nm) interlayer spacings likely arises from the localized nature of TEM compared to the bulk averaging of XRD, as well as peak broadening or asymmetry in the XRD data due to sample inhomogeneity or restacking.

The XRD pattern of Li/m-Fe_{0.2}Ta₂Se₂C after electrochemical lithiation (voltage profile is shown in Figure S3) indicated a significant shift in the (001) peaks toward lower angles (Figure 1a). The (001) peak at a 2θ of 9.96° shifted to about 5.52°, indicating an increase in d_{spacing} of 0.71 nm, which is due to the intercalation of Li between the layers. Here, we also noticed the peaks related to m-Fe_{0.2}Ta_2Se_2C (at $2\theta \sim$ 9.8°) and TaSe₂ (at $2\theta \sim 13.8^{\circ}$) structures, suggesting the presence of some unintercalated m-Fe_{0.2}Ta₂Se₂C and TaSe₂ in the sample. After Li-intercalation, deionized (DI) water was added to the sample while starting sonication. The addition of water results in the formation of LiOH (which is watersoluble) and H₂ gas. The mechanical force from ultrasonicinduced cavitation of the H₂ bubbles leads to the exfoliation of the layers.²⁸ After exfoliation, centrifuging the sample led to the separation of the few-layer sheets in the supernatant from multilayer particles and secondary phases in the precipitate. The inset in Figure 1a shows the supernatant exhibiting the Tyndall effect, suggesting the formation of a colloidal dispersion and a free-standing paper obtained after vacuumassisted filtration of the supernatant. A cross-sectional SEM image of the free-standing paper, shown in Figure S4g, reveals restacked layers due to vacuum-assisted filtration. XRD for the free-standing paper of 2D-Ta₂Se₂C (Figure 1a) shows a broadening and significant shifting of the early peak at 9.96° for m-Fe_{0.2}Ta₂Se₂C toward a lower angle of about 4.68°, which is due to the exfoliation of the multilayer structure to monolayers. Observation of broad and low-intensity. XRD peaks at lower angles in the 2D-Ta₂Se₂C paper indicate a less ordered restacking of the delaminated layers during the vacuum-assisted filtration process used to form the freestanding paper. All of the peaks, as marked in the XRD pattern, correspond to different (00*l*) planes of the Ta_2Se_2C phase. The peak at 35.07° corresponds to (111) planes of the TaC phase (PDF#00-035-0801). Freeze-drying the supernatant results in the formation of an aerogel. The SEM images for the aerogel sample in Figure S4e,f indicate a flaky morphology in the microscale, suggesting single- and/or few-layer sheets indicating the success of the delamination step. Figure 1d illustrates a few-layer sheet of Ta₂Se₂C captured by AFM. The height profile for an identified scan line is shown in the inset of Figure 1d. From the height profile, the sheet thickness was determined to be <4 nm, which indicates the measured sheet has few layers of thickness.

To gain better insight into the morphology and structure of 2D-Ta₂Se₂C, we used TEM and selected-area electron diffraction (SAED). Figure 1e shows a TEM image of a single sheet and the corresponding SAED pattern indicating the hexagonal symmetry which means the material has preserved its structure through the lithiation and exfoliation processes. 16,31,32 The SAED pattern of $2D\text{-}Ta_2Se_2C$ reveals a well-ordered hexagonal symmetry inherited from m-Fe_{0.2}Ta₂Se₂C, characteristic of high crystallinity. The HAADF-STEM plan-view image of a single layer, shown in Figure 1f, reveals a honeycomb arrangement of atoms. This is directly related to the arrangement of the Ta atoms, which dominate the image contrast through the Z^2 mechanism, in agreement with the SAED pattern. Figure S5b shows the individual and mixed elemental maps from STEM-EELS, with Ta in green and Se in red, revealing distinct alternating layers of Ta and Se, highlighting the layered structure characteristic of 2D-Ta₂Se₂C. Figure S5c,d presents a magnified view of the HAADF-STEM plan-view image of a single sheet of 2D-Ta₂Se₂C, along with its corresponding fast Fourier transform pattern. The atomic arrangement reveals a Ta-Ta spacing of 2.5 Å. Atomic defects such as vacancies and pinholes can be observed as dark spots, which can be useful as anchoring sites for single-atom catalysts as well as for tuning the material's properties, similar to what has been reported for other 2D materials.^{32–36} More TEM images of 2D-Ta₂Se₂C are provided in Figure S6a-d.

We used XPS measurements to gain a better understanding of the chemical nature of the elements on the surface of the sample and the chemical composition of the 2D sample. The survey spectrum (Figure S7) from -10 to 1350 eV indicated the presence of Ta, Se, C, Fe, Li, and Cu in the sample. Highresolution XPS spectra for the Ta-4f region (Figure 1g) can be deconvoluted using 8 peaks. The doublets at 22.6 and 24.69 eV correspond to $4f_{7/2}$ and $4f_{5/2}$, respectively. These peaks were assigned to Ta₂Se₂C since they are located between the peaks for TaC³⁶ and TaSe₂.^{37,38} The peaks at 23.2 and 25.74 eV correspond to TaSe₂.^{37,38} The peaks at 29.14 and 26.36 eV originated from TaO₂³⁹ and Ta₂O₅⁴⁰ oxides with doublets at 28.27 and 29.14 eV, respectively. These oxides could have formed after the solid-state synthesis as native oxides like what has been reported for layered carbides,^{41,42} during etching, delamination, and/or sample preparation for XPS. The highresolution XPS spectra for the Se-3d region (Figure 1h) can be fitted using 6 main peaks. The peaks at 53.4 and 54.3 eV correspond to $3d_{5/2}$ and $3d_{3/2}$, respectively. These peaks were assigned to Ta_2Se_2C .¹⁶ The other doublets at 54.05 and 54.91 eV are related to TaSe₂. The peaks at 55.76 and 55.89 eV correspond to $SeO_{x^*}^{43,44}$ TaSe₂ was formed during the solidstate synthesis process and the SeO_r peak is related to surface oxidation that can occur during etching and or delamination, handling, and or sample preparation for XPS measurements, which leads to Se vacancy formation.⁴³ Fitting the C 1s spectrum in Figure 1i resulted in five peaks. The peak at 282.6 eV was assigned to Ta2Se2C. The second peak at higher binding energy, located at 284.4 eV, is related to the C 1s peak for C-C and or C-H chemical bonds.⁴⁵ The peaks at 285.9, 287.4, and 288.4 eV were related to C–OH or C–O–C, C= O, and O–C=O, respectively.^{45,46}

The high-resolution XPS spectra of the Fe 2p region (Figure S8) were very weak, indicating the small amount of Fe in the sample with a Fe/Ta molar ratio of 0.196:1.00 obtained from XPS quantification (Table S5), and in agreement with EDS

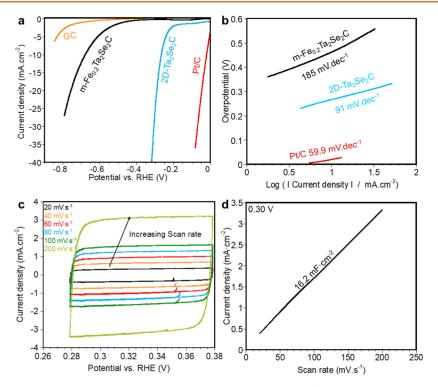


Figure 2. Electrochemical performance of Ta_2Se_2C as an electrocatalyst for HER. (a) LSV curves for glassy carboy (GC), Pt/C, m-Fe_{0.2}Ta₂Se₂C, and 2D-Ta₂Se₂C with H₂ bubbling after 20 CVs at OCP \pm 50 mV in a 3-electrode cell with a 0.5 M H₂SO₄ electrolyte with Hg/ Hg₂SO₄ in saturated K₂SO₄ as the reference electrode and Pt wire as the counter electrode. (b) Tafel polarization curves derived from LSV curves for m-Fe_{0.2}Ta₂Se₂C and 2D-Ta₂Se₂C. (c) CVs at different scan rates of 20, 40, 60, 80, 100, and 200 mV·s⁻¹ at the potential window of 0.28–0.38 V (OCP \pm 50). (d) Current density versus scan rate plot corresponding to 0.30 V extracted from CVs at different scan rates.

(Table S3) and inductively coupled plasma mass spectrometry (ICPMS) (Table S6) results. The observed increase in relative Fe content in the delaminated sample is likely due to the removal of TaC during the delamination process, which does not contain Fe. This results in a relative enrichment of Fe in the remaining sample despite the absolute Fe content remaining unchanged.

The Fe 2p region can be resolved into two main peaks corresponding to Fe⁰ and Fe³⁺ (Fe₂O₃) at 706.9 and 709.5 eV, respectively, along with their associated doublets at 719.7 and 722.7 eV, respectively. Since Li 1s overlaps with Se 3d, it was not possible to study Li using XPS. Thus, we used ICPMS (Table S6) to quantify the residual Li content in the 2D-Ta₂Se₂C sample and found the molar ratio of Li/Ta to be 0.38:1.00.

The UV-vis spectra for m-Fe_{0.2}Ta₂Se₂C and 2D-Ta₂Se₂C in DI water are shown in Figure S10, clearly illustrating differences in absorption behavior. While both materials exhibit strong UV absorbance, 2D-Ta₂Se₂C retains significantly higher absorbance in the visible and near-infrared regions than $m-Fe_{0.2}Ta_2Se_2C$ and Ta_2O_5 .⁴⁶ According to the literature, Ta₂O₅^{46,47} displays minimal absorbance beyond the UV range, typical of a bulk wide-bandgap insulator. The enhanced visible and near-infrared absorbance in 2D-Ta₂Se₂C suggests quantum confinement effects or surface plasmon resonances, which are absent in the bulk-like m-Fe_{0.2}Ta₂Se₂C and Ta₂O₅.^{46,47} The higher absorbance for 2D-Ta₂Se₂C across the visible spectrum, compared to both m-Fe_{0.2}Ta₂Se₂C and Ta₂O₅,^{46,47} may be attributed to the unique electronic and structural properties introduced by the 2D exfoliation process, leading to increased light-matter interactions and potentially more active sites for electronic transitions.⁴⁸ However, the semifeatureless UV-vis

might be explained by the presence of other bulk phases coexisting with delaminated materials.⁴⁹ These bulk phases are most likely TaC, which was detected in the XRD patterns after delamination and centrifugation. Additionally, a small amount of undelaminated m-Fe_{0.2}Ta₂Se₂C particles which cannot be detected in the XRD patterns might also coexist with the delaminated materials. Thus, further systematic studies are required to purify the samples after delamination and to eliminate any bulk phases. Such studies might involve varying sonication time and frequency, centrifugation speed, and solvent type.⁵⁰

The electrical conductivity values obtained using the fourprobe method are listed in Table S7. For m-Fe_{0.2}Ta₂Se₂C, the conductivity was found to be 2.75 S·cm⁻¹, but it dropped to 0.46 S·cm⁻¹ after delamination (2D-Ta₂Se₂C). However, 2D-Ta₂Se₂C shows a slightly higher electrical conductivity than 2D-TaSe₂ (0.41 S·cm⁻¹). Potentiostatic electrochemical impedance spectroscopy (PEIS) measurements (Figure S9e) reveal the same trend with lower resistance for m-Fe_{0.2}Ta₂Se₂C $(0.38 \ \Omega \cdot cm^2)$ compared to that for 2D-Ta₂Se₂C $(0.58 \ \Omega \cdot cm^2)$ and 2D-TaSe₂ (0.71 Ω ·cm²). Here, we also see a slightly lower resistance for 2D-Ta₂Se₂C compared to that for 2D-TaSe₂. This behavior is explained by the oxidation of samples during the etching and delamination, as well as the loss of van der Waals interactions between layers, reducing electron mobility, while selenium vacancies introduce midgap defect states that trap charge carriers and further hinder conductivity. These vacancies are particularly detrimental in both Ta2Se2C and TaSe₂, correlating with the sharp decline in conductivity, as they disrupt the metallic interlayer coupling and charge transport pathways, a phenomenon observed across many TMD systems.⁵¹ However, multilayer and delaminated TaSe₂

and Ta_2Se_2C samples show low electrical conductivities across all samples, largely probably due to selenium vacancies and oxidation of the samples introduced during the etching process used to remove intercalated Fe atoms.

Electrocatalytic Performance for HER. Here, we focused on the electrochemical performance of Ta₂Se₂C as an electrocatalyst for HER. Figure 2a illustrates the linear sweep voltammetry (LSV) diagrams for m-Fe_{0.2}Ta₂Se₂C and 2D-Ta₂Se₂C when used as an electrocatalyst for HER while bubbling H₂. LSV values for glassy carbon (GC) and Pt/C electrodes were also plotted for comparison. The LSV diagrams were collected after 20 cyclic voltammograms (CVs) in the range of open-circuit potential (OCP) \pm 50 mV to eliminate the effect of any possible reactions in the system during LSV measurements. The LSV was carried out in a 3-electrode cell using H₂ gas bubbling. The overpotential (η_{10}) of Ta₂Se₂C decreased from 678 to 264 mV due to delamination from m-Fe_{0.2}Ta₂Se₂C to 2D-Ta₂Se₂C, respectively. The two distinct slopes in the LSV for the delaminated sample, with significant current observed in the 0 to -0.3 V range, indicate an increased surface area and a higher density of active sites compared to the multilayer sample. The early onset of current can be attributed to better accessibility to catalytic sites or surface defects introduced by the delamination process, as suggested by previous studies on the effect of increased surface area and delamination on catalytic performance.⁵² Since the Pt counter electrode might affect the accuracy of overpotential measurements, especially in acidic electrolytes,^{53,54} we repeated LSV measurements using a graphite rod counter electrode (Figure S9a). A slightly lower overpotential of 252 mV was observed compared to the LSV measurement using the Pt wire counter electrode (264 mV).

The promising performance of 2D-Ta₂Se₂C indicates that delaminating Ta₂Se₂C and exposing more catalytic active sites remarkably improve its performance for HER and is comparable to previously reported electrocatalysts for HER.^{9,55–58} For example, Thangasamy et al. exfoliated MoS₂ powder using sonication at different dispersion media achieving an η_{10} of 570 to 720 mV.⁵⁵ In another study, Thangasamy et al. used a solvothermal approach to produce a rose-like shape MoS₂ nanostructure, resulting in an η_{10} of 330 mV.⁵⁵ Chen et al. synthesized TaS₂ by electrochemically exfoliating bulk TaS₂ using an alternating voltage in an acidic electrolyte, with an η_{10} of 370 mV on GC.⁵⁶

To further understand the HER kinetics and inherent activities of m-Fe_{0.2}Ta₂Se₂C and 2D-Ta₂Se₂C samples for the HER, Tafel polarization curves were plotted using data from LSV curves (Figure 2b). The Tafel slope for 2D-Ta₂Se₂C in the presence of H₂ gas in the system was calculated to be 91 $mV \cdot dec^{-1}$, indicating the HER kinetics is controlled by the Volmer step⁵⁷ and much lower than m-Fe_{0.2}Ta₂Se₂C (185 mV· dec⁻¹). This indicates the higher intrinsic activity of 2D-Ta₂Se₂C due to the synergistic effect of the large, exposed surface area, the presence of iron as single atoms, and vacancies in the structure, which provide a more open structure. As reported in the literature for TMDs, vacancies enhance the catalytic activity in HERs by creating active sites and altering the electronic structure. Sulfur (S) and Selenium (Se) vacancies in 2D-TMDs lower hydrogen adsorption energy, making the surface more reactive and improving the efficiency of hydrogen adsorption and desorption.⁵⁸ These vacancies also increase the number of available edge sites, which are crucial for efficient HER catalysis. Similarly, in TMCCs, tuning the

vacancy concentration can potentially optimize the catalytic performance of 2D-TMCCs, making them promising candidates to replace noble metal catalysts in the HER. Understanding the role of Se vacancies in 2D-Ta₂Se₂C is essential for enhancing its catalytic efficiency in hydrogen evolution. Further investigation into how these vacancies affect the material's electronic properties and catalytic activity will provide deeper insights into its performance and guide the development of more efficient catalysts for energy conversion applications.^{58,59}

Then, CVs at different scan rates of 20, 40, 60, 80, 100, and 200 mV $\cdot s^{-1}$ were measured for 2D-Ta_2Se_2C (Figure 2c) with bubbling H₂. H₂ purging was performed to saturate the electrolyte, ensuring a consistent electrocatalytic performance. To confirm that this does not affect the accessibility to active sites, we measured the CVs with and without bubbling H_{2} , and the results were nearly identical (Figure S9b). The CVs show almost the same capacitance, indicating that the low flow rate of H₂ bubbling used in this experiment does not hinder the accessibility of the active sites. By extracting the values of the difference between anodic and cathodic current densities at 0.30 V corresponding to different scan rates, we obtained the plot in Figure 2d. Assuming no Faradaic reaction contribution, the slope of this line is equal to the double-layer capacitance $(C_{\rm dl})$.⁶⁰ A $C_{\rm dl}$ of about 16.2 mF·cm⁻² was measured, corresponding to a specific electrochemically active surface area (ECSA) of 17.61 $m_{ECSA}^2 \cdot g_{catalyst}^{-1}$ (details of the calculations and assumptions are provided in the Supporting Information). Compared to the theoretical specific surface area of 212.82 m²·g⁻¹, the lower ECSA estimated here suggests incomplete utilization of Ta₂Se₂C or that the basal plane might not be the active site for HER. The ECSA and $C_{\rm dl}$ values are higher than what was reported for ultrathin $Ti_3C_2T_x$ MXene $(\text{ECSA} = 12.07 \text{ m}_{\text{ECSA}}^2 \cdot \text{g}_{\text{catalyst}}^{-1}), \text{ MoS}_2 (2 \text{ m}_{\text{ECSA}}^2 \cdot \text{g}_{\text{catalyst}}^{-1}),$ and TaSe₂ nanobelts $(13.12 \text{ m}_{\text{ECSA}}^2 \cdot g_{\text{catalyst}}^{-1})$,⁶¹ indicating the high effective surface area of the 2D-Ta₂Se₂C electrocatalyst. Table S8 compares the electrocatalytic performance of 2D-Ta₂Se₂C with various 2D-TMDs reported in the literature, demonstrating that 2D-Ta₂Se₂C exhibits a performance on par with some of the most active 2D-TMDs. Also using CVs at different scan rates, the capacitance versus potential graph was extracted (Figure S9c), demonstrating uniform capacitance behavior across the scan rates.

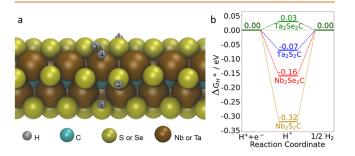
The chronoamperometric stability graph for D-Ta₂Se₂C in Figure S9d reveals promising electrochemical stability under continuous operation at room temperature under H₂ bubbling at a constant applied potential of -0.3 V. The initial sharp decrease in current density observed in the first few hundred seconds likely represents the formation of a stable electrochemical double layer and the initial activation of surface sites. Following this, the current stabilizes, with a gradual increase, suggesting that the material undergoes further surface restructuring or stabilization of active sites, improving its conductivity and catalytic activity over time. Importantly, the absence of significant fluctuations or current decay throughout the 1500 s test indicates that 2D-Ta₂Se₂C exhibits durable electrochemical performance without apparent degradation. This stable behavior suggests that 2D-Ta₂Se₂C can maintain its activity over extended electrochemical cycles, making it a strong candidate for applications requiring sustained electrochemical activity, such as in energy conversion or storage technologies.

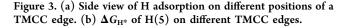
To compare the chemical stabilities of 2D-Ta₂Se₂C and 2D-TaSe₂, the colloidal dispersion obtained after delamination was stored at room temperature for several days, and photographs were taken at different time intervals (Figure S11). The results showed that the 2D-TaSe₂ solution began to change color within the first few hours, indicating lower stability compared to that of 2D-Ta₂Se₂C, which exhibited almost no color change even after several days.

The turnover frequency (TOF) versus potential graph obtained from the LSV results for 2D-Ta₂Se₂C in Figure S9f shows that the TOF increases as the applied overpotential increases from -0.2 V vs reversible hydrogen electrode (RHE) to more negative (-0.38 V vs RHE). This suggests that the catalytic activity improves significantly at more negative potentials, indicating an enhanced reaction kinetics in this region. The red plot is when we consider the Se sites at the edge to be active (0.4% of the total amount of Se), and the blue plot is when we consider the Se sites at the basal plane to be active (details of the calculations and assumptions are provided in the Supporting Information).

It is worth noting that, as discussed earlier, bulk phases such as TaC particles, which are not known to be effective catalysts for HER, 62 coexisted with delaminated Ta₂Se₂C. Therefore, it is reasonable to predict that better performance can be achieved by further purifying the sample and synthesizing higher-purity materials. Another factor that might contribute to the electrocatalytic behavior of the studied materials is the presence of small amounts of lithium and iron in the sample. Iron is known to be an effective catalyst for HER, particularly when used as a single-atom catalyst.⁶³ For instance, an overpotential as low as 9 mV and a favorable Tafel slope of $37.8 \text{ mV} \cdot \text{dec}^{-1}$ were reported for iron/graphdiyne.⁶⁴ However, the iron residues from the solid-state synthesis step of bulk Ta₂Se₂C, which persisted in the materials after delamination, are not expected to lead to single-atom dispersion of iron on the surface of Ta₂Se₂C sheets. Instead, they likely form particles of iron and iron oxide, as observed through XPS analysis. Further studies are needed to understand the nature of iron and lithium in TMCCs and their effect on the electrochemical behavior of TMCCs.

DFT Calculations. To gain atomistic insight into the reactivity trends and the likely active sites, H adsorption on various TMCCs (Ta_2Se_2C , Ta_2S_2C , Nb_2Se_2C , and Nb_2S_2C) was calculated by DFT. The TMCCs were modeled including an edge so that both edge and plane sites could be studied. One H atom was placed at various positions, and 5 relatively low-energy converged structures were found, as shown in Figure 3a. H(1) is on top of a surface S/Se, similar to adsorption on the basal plane of a 2D surface; H(3) is bridging





an S/Se and a metal atom at the edge; H(4) is on top of a metal atom at the edge; H(2) and H(5) are binding to two different edge S/Se atoms. The calculated ΔG_{H^*} values at these 5 positions for the four TMCCs are listed in Table S9. Among the 5 positions, H(5) always had the strongest adsorption, and its ΔG_{H^*} was the closest to 0. This indicates that H(5), an S or Se edge site, is likely to be most active for HER. The ΔG_{H^*} of H(5) on 4 TMCC edges are shown in Figure 3b, with an order of $Ta_2Se_2C > Ta_2S_2C > Nb_2Se_2C > Nb_2S_2C$. The results indicate that the TMCC with Nb has stronger adsorption than Ta, and S has stronger adsorption than Se. Ta₂Se₂C is the nearest to the zero level, which suggests it would have the highest catalytic performance for HER among the 4 materials. The Ta₂Se₂C sites have an H adsorption energy quite close to 0, which might be expected to lead to an overpotential close to 0. However, the H adsorption energy alone is not quantitatively accurate in predicting electrocatalytic performance, as the details of the mechanism and transition states and the effect of the complex electrocatalytic environment all play a role in determining the performance.⁶

To gain insight into how the C core may generally lead to conductivity in TMCCs, we calculated the projected density of states (PDOS) for Ta₂Se₂C and 1H–TaSe₂ (Figure S12). 1H– TaSe₂ is itself metallic, and our calculations correctly capture this (see Figure S12b) as do previous calculations.⁶⁶ Our calculations also correctly predict Ta₂Se₂C to be metallic (see Figure S12a). In Ta_2Se_2C , we found that the C core did not directly contribute to a large number of states in the region around the Fermi energy but instead modified the PDOS on the other two elements. Specifically, TaSe₂ shows more isolated peaks with gaps between them, while for Ta₂Se₂C, there is more overlap between peaks and fewer gaps. This smoother behavior with few gaps was also seen in previous PDOS calculations of TMCCs.⁶⁷ This reduction in the number of gaps would be expected to generally promote metallic behavior, consistent with the more metallic nature of TMCCs as compared to TMDs.

CONCLUSIONS

In summary, to obtain efficient electrocatalysts containing core carbon layers of MXenes which provide high electrical conductivity as well as stability and the surface layer of TMDs which provides high electrochemical activity, we produced multilayer Ta2Se2C for the first time through a simple scalable and rapid solid-state thermal process under atmospheric pressure. Ta, TaC, and FeSe were mixed, pressed, and heated for 4 h at 1200 °C. Most of the iron in the secondary phase and the iron between the layers were removed by etching in 3 M H₂SO₄. Electrochemical Li-intercalation followed by sonication in DI water exfoliation led to the synthesis of Ta₂Se₂C mono-/few-layer sheets. Comparing measured and theoretically calculated XRD patterns confirmed the formation of the hexagonal Ta_2Se_2C structure ($P\overline{3}m1$ space group). Microscopy techniques illustrated the layered hexagonal structure of the multilayer sample and few-layer sheets for the delaminated sample with about 4 nm thickness. STEM-EELS quantified a Ta/Se ratio of almost 2.0:1.8, suggesting Se vacancies in the structure most likely formed during the purification and liquid exfoliation procedures.

We investigated the electrocatalytic performance of the drop-casted sample on a GC electrode which illustrated an improved HER electrocatalytic performance of 2D-Ta₂Se₂C ($\eta_{10} = 264$ mV), compared to the multilayered Ta₂Se₂C ($\eta_{10} =$

678 mV), due to a synergistic effect of inherent catalytic performance of the material possibly as a result of high electrical conductivity and catalytic activity, and an ECSA of about 17.61 m_{ECSA}² g_{catalyst}⁻¹. Using DFT calculations to analyze reactivity trends and active sites for H adsorption on various TMCCs, we identified five potential active sites, with the strongest adsorption occurring at the binding edge S/Se atoms, exhibiting an adsorption free energy of 0.03 eV. This suggests that these sites are the most active for HER. Comparison among different TMCCs revealed Ta₂Se₂C as the top performer for HER catalysis, with the order of catalytic activity as Ta₂Se₂C > Ta₂S₂C > Nb₂Se₂C.

Our study proposes a scalable synthesis method for multilayer and 2D-TMCCs or TMCC nanoparticles, facilitating the design of efficient electrocatalysts for the HER and likely other energy storage applications.

EXPERIMENTAL SECTION

Synthesis of Multilayer Fe, Ta, Se, C. A simple solid-state method was used to synthesize Fe_xTa₂Se₂C. In a typical procedure, Ta (Alfa Aesar, <44 μm , 99.9% purity), TaC (Alfa Aesar, <44 μm , 99.9% purity), and FeSe (Thermo Scientific, <420 μ m, 99.9% purity) powders were weighed in an argon (Ar)-filled glovebox under an ultrahigh-purity (UHP) Ar atmosphere. Powders in the molar ratio of Ta/TaC/FeSe = 1.0:1.0:2.0 (each batch was 10 g) were placed in a 30 mL high-density polyethylene (HDPE) jar containing 20 yttriumstabilized zirconia balls of 5 mm diameter each. The HDPE jar was closed and sealed using parafilm and removed from the glovebox for mixing. A Turbula T2F mixer at \approx 56 rpm for 3 h was used to mix the powders. Then, the jar was transferred to the glovebox again, and the powders were pressed into a 1" diameter pellet under 350 bar, put in an alumina crucible, and transferred in a sealed container to a tube furnace that was in a well-ventilated chemical fume hood. The sample was heated to 1200 °C at a heating rate of 10 °C·min⁻¹ and held at 1200 °C for 4 h, and then the furnace was allowed to cool to room temperature. The heating and cooling treatments were carried out under a continuous Ar flow of about 3 L·min⁻¹. Other synthesis conditions for Fe_xTa₂Se₂C, including different precursor compositions, synthesis temperatures, and times, were explored and are listed in the Supporting Information (Table S1). The method used to synthesize Fe_xTaSe₂ is explained in Supporting Information and the corresponding XRD plot is provided in Figure S2.

To remove excessive iron, the sample was ground to -325 mesh (<44 μ m), and 1 g of Fe_xTa₂Se₂C powder was gradually added to 20 mL of 3 M H₂SO₄ and stirred for 24 h at room temperature. The mixture was sonicated every few hours for 1 min to facilitate acid penetration into the powder particles with a total sonication duration of 5 min. Then, the acid was replenished, and the procedure was repeated for another 24 h. Then, the solution was centrifuged at 3500 rpm for 3 min, the acid was decanted, and settled powders were washed with DI water to pH \approx 7 and vacuum filtered on a Whatman filter paper grade 2 overnight.

Synthesis of 2D-Ta₂Se₂C. To exfoliate the layers of Ta₂Se₂C and obtain single- or few-layer sheets, we used the electrochemical Liintercalation technique (voltage profile in Figure S3) followed by exfoliation via sonication in DI water. About 120 mg of the multilayer powder was pressed to a free-standing 1" diameter wafer under 500 bar. The wafer was transferred to an Ar-filled glovebox ($O_2 < 0.1$ ppm, $H_2O < 0.1$ ppm). The schematic configuration of the electrochemical cell (EL CELL) is shown in Scheme \$1. A stainless-steel disk of 14 mm diameter was used as the bottom-part current collector. Both sides of a Li wafer were brushed to get a shiny surface and pressed on the stainless-steel disk to attach to it and get a mirror-like surface. A glass microfiber filter (Whatman CAT no. 1823–047 GF/D, 2.7 µm) was placed on the Li wafer, and 100 μ L of 1 M LiPF₆ in ethylene carbonate and ethyl methyl carbonate (EMC) (EC/EMC equaled 3:7 by volume) was dropped all over the separator as an electrolyte. Then, the free-standing wafer and a copper foil of 1" diameter were added as

the working electrode and current collector, respectively. The cell was sealed tightly, removed from the glovebox and connected to a potentiostat-galvanostat (VMP3, BioLogic). Galvanostatic cycling with potential limitation (GCLP) was conducted with a low discharge rate of 5 mA \cdot g⁻¹ started from the OCP to a cutoff potential of 0.1 V vs Li/Li⁺. During discharge, Li intercalates between the layers of Ta₂Se₂C. Figure S3 shows the voltage profile for a 120 mg wafer. After reaching the cutoff potential, the EL CELL was disconnected and transferred to the glovebox, and the working electrode was removed from the EL CELL, soaked in diethyl carbonate (DEC) to rinse off any remaining salts, removed from DEC, cleaned gently with Kimwipe, and then put in a 50 mL centrifuge tube. The tube cap was tightened before removal of the tube from the glovebox and transferred to an ultrasonic bath. Sonication at 37 MHz was started while adding 50 mL of DI water to the tube. A 5 min sonication followed by one h centrifugation at 5000 rpm was conducted as the first cycle. The supernatant was separated and discarded, 50 mL of DI water was added to the sediment and redispersed, and the second cycle was conducted with 5 min sonication and a 30 min centrifugation at 3500 rpm. The supernatant was collected in a bottle. 50 mL of DI water was added to the sediment, and the previous cycle of sonication and centrifugation was repeated until a clear liquid was obtained after centrifugation. Finally, the collected liquid was filtered or freeze-dried. The material on the filter formed a free-standing paper, and the material from the freeze drier formed an aerogel. The schematic procedure used here for synthesizing 2D-Ta₂Se₂C is provided in Scheme 1.

Characterization of Multilayer and Delaminated Ta₂Se₂C. A Cu K_a X-ray diffractometer Rigaku D/Max-2200 was used to collect XRD patterns at a 2θ step size of 0.02° and a sweep rate of $1^{\circ} \cdot \min^{-1}$ at operation conditions of 40 kV and 40 mA. SEM images were captured using a Hitachi S-4800 with an acceleration voltage of 3 kV. For elemental analysis, we used an SEM Hitachi S-3400 equipped with an energy-dispersive X-ray spectroscopy detector (EDS, Oxford, UK) at an accelerating voltage of 30 kV connected to INCA software. Elemental concentrations were determined using the Thermo Element2 high-resolution ICPMS at Tulane University's TINI department. Linear calibration curves were established for each element with a laboratory blank subtracted. The sample solution was prepared by dissolving 2D-Ta₂Se₂C in an aqua regia solution with hydrofluoric acid addition. Results were reported as parts per billion after appropriate dilution using 2% nitric acid. A solution of 0.6 g·L⁻¹ was prepared, and UV-vis absorption spectra were recorded using a UV-1700 PharmaSpec UV-vis Spectrometer (Shimadzu Corporation), equipped with UVProbe software (Version 2.35) for data acquisition and analysis.

TEM images were captured by an FEI TECNAI G2-F30 transmission electron microscope at an accelerating voltage of 200 kV. To get a better understanding of the elemental composition and the atomic-scale configuration of the structure, EELS together with STEM imaging using a HAADF detector was carried out using the Linköping double C_s -corrected FEI Titan³ 60–300 microscope operated at 300 kV and the embedded GIF Quantum ERS. The probe maintained a convergence angle of 21.5 mrad throughout the imaging and EELS acquisition. EELS spectrum images (SIs) were acquired for 5 min using 0.1 nA beam current, 0.25 eV/channel energy dispersion, 0.2 s pixel dwell time, and a 55 mrad collection semiangle. To prepare the sample, a multilayer powder was mixed with distilled water to make a liquid suspension. Then the liquid suspension was sonicated for 2 min to break the large Ta2Se2C multilayers into small particles to avoid charging issues. A few drops from the liquid suspension were then dropped onto the copper lacey carbon grid (300 mesh) and allowed to dry for a few minutes. Then, the grid was loaded into a standard double-tilt holder and introduced into the microscope.

For surface chemistry investigation, we used X-ray photoelectron spectroscopy (XPS, Thermo Fisher, USA) with an Al K_{α} X-ray source at a 200 eV pass energy, a step of 1 eV, and a spot size of 400 μ m. The XPS sample was prepared by drop-casting a diluted slurry of the aerogel sample in a nonaqueous liquid on a copper substrate, dried in

a vacuum under an Ar environment, and exposed to ion-irradiation for charge neutralization, followed by a 5 min Ar^+ sputtering to remove the surface and clean any probable contaminants during sample preparation. CasaXPS software was used for the XPS data analysis and peak fitting.

The samples for transmission electron microscopy (TEM) studies were prepared from the fresh supernatant after delamination and centrifugation, and just extra ethanol was added to dilute the supernatant. The colloidal dispersion of 2D-Ta₂Se₂C was then dropcast onto a TEM copper grid. A multimode atomic force microscope (Bruker Dimension ICON, USA) was used to image the single sheets and measure their thickness. The atomic force microscopy (AFM) sample was prepared by spray-coating DI water-diluted 2D-Ta₂Se₂C colloidal dispersion after exfoliation onto an Ar plasma-cleaned Si substrate. The AFM tip (PPP-NCHR-10, NANOSENSORS) operated under tapping mode to collect the AFM image.

The electrical conductivity of the samples was measured using a ST2253 digital four-probe resistivity meter.

Performance for HER. The electrochemical activities of multilayer and delaminated Ta₂Se₂C were investigated using standard three-electrode cells. Electrodes of drop-cast samples on a rotating disk of glassy carbon (RDGC) were used as the working electrodes. Platinum wire and Hg/HgSO₄ in saturated KCl were used as counter and reference electrodes, respectively. An aqueous 0.5 M H₂SO₄ solution was used as the electrolyte. Before electrochemical measurements were started, the electrolyte was bubbled with H₂ or Ar gas for at least 30 min and kept bubbling during measurements. The cell was connected to a BioLogic Potentiostat-Galvanostat equipped with EC-lab software.

To prepare the working electrodes, 10 mg of each sample was added to a solution containing 100 μ L of DI water, 90 μ L of ethanol, and 10 μ L of Nafion solution (alcohol-based, 1000 EW at 5 wt %, ION POWER). The slurry was sonicated for 15 min at 25 °C. Then, 3.3 μ L of the slurry was dropped on the surface of a mirror-like polished RDGC with a 3 mm diameter and dried under ambient conditions for about 30 min (loading ~2.3 mg·cm⁻²).

To investigate the electrochemical performance, first, the OCP of the cell was measured, and 20 CVs were performed with a potential window of OCP ±50 mV at a scan rate of 20 mV·s⁻¹. LSV was conducted at a scan rate of 5 mV·s⁻¹ in a potential window of 0 to -0.8 V vs RHE. The PEIS was performed at a range of 100 kHz to 100 mHz with a sinus amplitude of 10 mV to appraise the reaction kinetics and to measure the charge transfer resistance ($R_{\rm ct}$) at the electrode/electrolyte interface,⁶⁸ and all the potential values were *iR*-corrected and reported versus RHE according to $R_{\rm ct}$ obtained from the PEIS measurements. The current values were converted to the geometric current density. The Tafel polarization slope was calculated from the LSV data. CVs at different scan rates were recorded, and from that, the $C_{\rm dl}$ of each material was extracted in the nonfaradaic region, and from that, the ECSA was calculated.⁶⁹

Computational Method. All calculations in this work were performed applying DFT with the Perdew, Burke, and Ernzerhof generalized gradient functional (GGA-PBE)⁷⁰ with the Tkatchenko–Scheffler method⁷¹ for van der Waals interactions. A $7 \times 1 \times 1$ k-point mesh was used with a 400 eV cutoff energy. All calculations were done using the Vienna Ab initio Simulation Package (VASP),⁷² and structures were visualized using Visual Molecular Dynamics.⁷²

In this work, a 3×3 unit cell was used containing nine M_2S_2C or M_2Se_2C formula units (M = Nb or Ta). Roughly 12 Å of vacuum was inserted in the *y*-direction to form an edge and the *z*-direction to separate the layers. All atoms were relaxed during optimization. The Gibbs free energy (300 K) of hydrogen adsorption was defined as

$$\Delta G_{\mathrm{H}^*} = G_{\mathrm{TMCC-H}} - G_{\mathrm{TMCC}} - 1/2G_{\mathrm{H2}}$$

where $G_{\text{TMCC-H}}$ is the free energy of a TMCC with an adsorbed H atom, G_{TMCC} is the free energy of the clean TMCC, and G_{H2} is the free energy of the hydrogen molecule in the gas phase. The free energy *G* was calculated as

where E is the electronic energy, ZPE is the zero-point energy, T is the temperature, and S is the entropy.

ASSOCIATED CONTENT

Supporting Information

The Supporting Information is available free of charge at https://pubs.acs.org/doi/10.1021/acsnano.4c09903.

Further details on the synthesis, characterization, and additional electrochemical results for Ta_2Se_2C and $TaSe_2$ and calculations for ECSA, theoretical specific surface area, and TOF for 2D Ta_2Se_2C (PDF)

AUTHOR INFORMATION

Corresponding Author

Michael Naguib – Department of Physics and Engineering Physics, Tulane University, New Orleans, Louisiana 70118, United States; orcid.org/0000-0002-4952-9023; Email: naguib@tulane.edu

Authors

- Elham Loni Department of Physics and Engineering Physics, Tulane University, New Orleans, Louisiana 70118, United States
- Ahmad Majed Department of Physics and Engineering Physics, Tulane University, New Orleans, Louisiana 70118, United States
- Shengjie Zhang Department of Chemical and Biomolecular Engineering, Tulane University, New Orleans, Louisiana 70118, United States
- Hari H. S. Thangavelu Department of Physics, Chemistry and Biology, Linköping University, Linköping SE-581 83, Sweden
- Chaochao Dun − The Molecular Foundry, Lawrence Berkeley National Laboratory, Berkeley, California 94720, United States; • orcid.org/0000-0002-3215-6478
- Anika Tabassum Department of Physics and Engineering Physics, Tulane University, New Orleans, Louisiana 70118, United States
- Karamullah Eisawi Department of Physics and Engineering Physics, Tulane University, New Orleans, Louisiana 70118, United States; o orcid.org/0000-0002-9031-4809
- Jeffrey J. Urban The Molecular Foundry, Lawrence Berkeley National Laboratory, Berkeley, California 94720, United States; Ocicid.org/0000-0003-4909-2869
- Per O. Å. Persson Department of Physics, Chemistry and Biology, Linköping University, Linköping SE-581 83, Sweden; Orcid.org/0000-0001-9140-6724
- Matthew M. Montemore Department of Chemical and Biomolecular Engineering, Tulane University, New Orleans, Louisiana 70118, United States; Orcid.org/0000-0002-4157-1745

Complete contact information is available at: https://pubs.acs.org/10.1021/acsnano.4c09903

Author Contributions

The manuscript was written through the contributions of all authors. All authors have given approval to the final version of the manuscript.

Notes

The authors declare no competing financial interest.

This work was supported by the National Science Foundation under grant no. DMR-2048164. The computational work was supported by Tulane University and the National Science Foundation through grant no. CHE-2154952. The authors acknowledge the Swedish Research Council (VR) and the Swedish Foundation for Strategic Research (SSF) for access to ARTEMI, the Swedish National Infrastructure in Advanced Electron Microscopy (nos. 2021-00171 and RIF21-0026). POÅP also acknowledges VR for project funding (2021-04499). Work at the Molecular Foundry was supported by the Office of Science, Office of Basic Energy Sciences, of the U.S. Department of Energy under Contract No. DE-AC02-05CH11231.

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